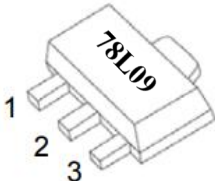


Features ➢ 采用50V工艺平台制造 ➢ 宽输入电压范围：10.50-35V输入 ➢ 全电压、全电流、全温下输出电压冗余范围±5% ➢ 稳定输出电流达 100mA ➢ 内建过温保护、过压保护、过流保护	Max V_{in}	V_o	ID
	35V	9V	100mA
Package  Marking and pin assignment	Application ➢ 仪器仪表 ➢ 主板电源 ➢ 设备电源模块 ➢ 多路电源系统		
			
	Pin No.	Name	Explication
	1	Vout	输出
	2	GND	芯片地
	3	Vin	输入

Package Marking and Ordering Information

Device Marking	Device	Device Package	Quantity
78L09	78L09	SOT89-3	1000

Absolute Maximum Ratings ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

Description	Symbol	Value range	Unit
输入电压	V_{in}	-0.30 ~ 35	V
最大结温	T_J	150	$^{\circ}\text{C}$
最大功耗	P_d	750	mW
热阻（结到环境）	$R_{\theta JA}$	160	$^{\circ}\text{C}/\text{W}$
工作温度范围	T_A	-40 ~ 85	$^{\circ}\text{C}$
存储温度范围	T_{STG}	-55 ~ 150	$^{\circ}\text{C}$

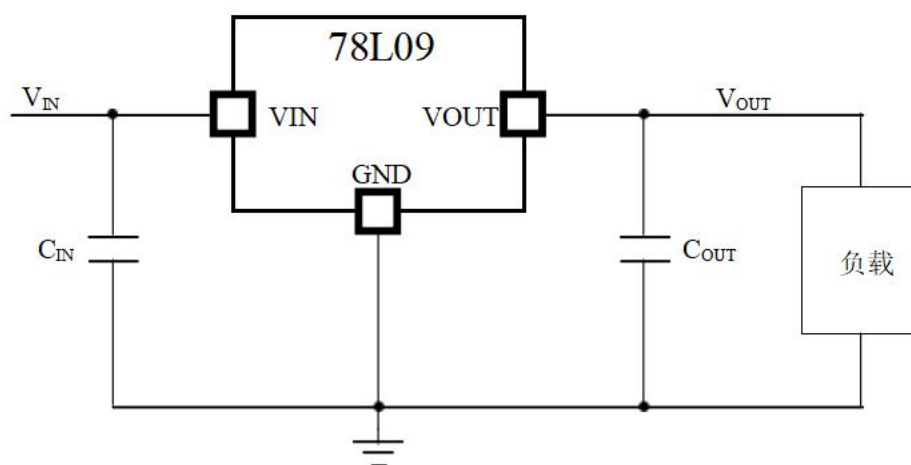
以上表格参数代表电路能够承受的极限范围。达到或者超过这个参数，电路不能正常工作，并且很大可能会损坏。并且长期工作在临界极限参数，也是会大大增加损坏的几率。

Electrical Characteristics ($T_J=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
输出电压	V_o	$V_{IN} = 12\text{V}, I_o = 40\text{mA}$	8.73	9.00	9.27	V
		$11\text{V} < V_{IN} < 25\text{V}$ $1\text{mA} < I_o < 40\text{mA}$	8.55		9.45	

		$1\text{mA} < I_O < 100\text{mA}$	8.55		9.45	
线性调整率	ΔV_O	$11\text{V} < V_{IN} < 25\text{V}, I_O = 10\text{mA}$		25	150	mV
		$11\text{V} < V_{IN} < 25\text{V}, I_O = 10\text{mA}$		15	100	
负载调整率	ΔV_O	$V_{IN}=11\text{V}, 1\text{mA} < I_O < 100\text{mA}$		30	100	mV
		$V_{IN}=11\text{V}, 1\text{mA} < I_O < 40\text{mA}$		8	50	
静态电流	I_Q			2.30	5	mA
静态电流变化	ΔI_Q	$11\text{V} < V_{IN} < 25\text{V}$		0.30	1	mA
		$1\text{mA} < I_O < 40\text{mA}$			1	
输出噪声电压	V_n	$f=10\text{Hz to } 100\text{KHz}$		70		μV
电源抑制比	PSRR	$f=100\text{Hz}, 11\text{V} < V_{IN} < 16\text{V}$	47	56		dB
峰值输出电流	I_{PK}			300		mA
电压温度系数	V_{TC}	$I_O = 10\text{mA}$		0.80		$\text{mV}/^\circ\text{C}$
低压差	V_{Drop}	$I_O = 100\text{mA}$		1.75	2	V
		$I_O = 200\text{mA}$		1.95	2.10	
最小输入电压	$V_{IN,MIN}$			10.50	11	V
过压保护阈值	$V_{IN,MAX}$	$I_O = 10\text{mA}$		42		V

Typical application



输出 9V 典型应用电路

Typical Characteristics ($C_{IN}=220nF$, $C_{OUT}=100nF$)

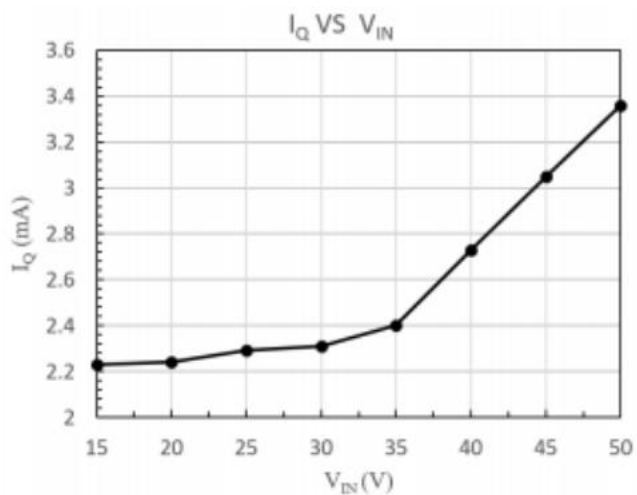


图 1 静态电流随输入电压变化

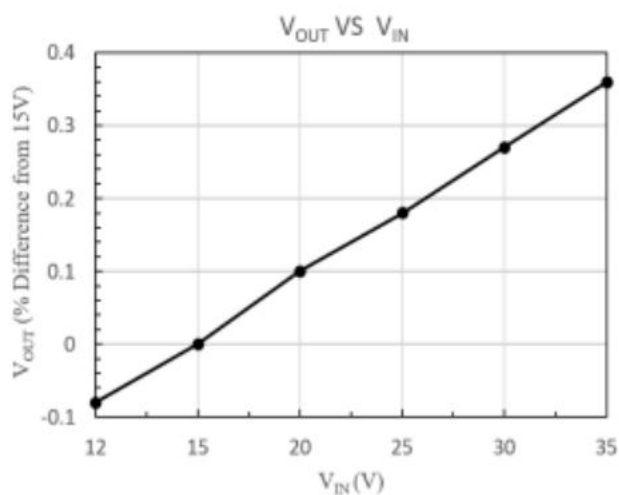


图 2 输出电压随输入电压变化 ($I_O=10mA$)

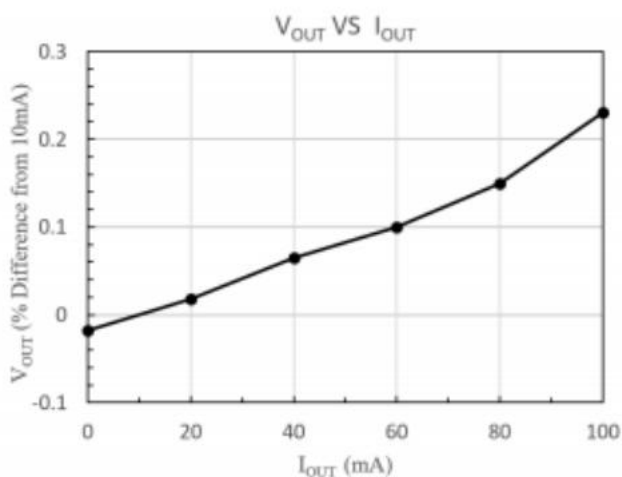


图 3 输出电压随负载电流变化 ($V_{IN}=12V$)

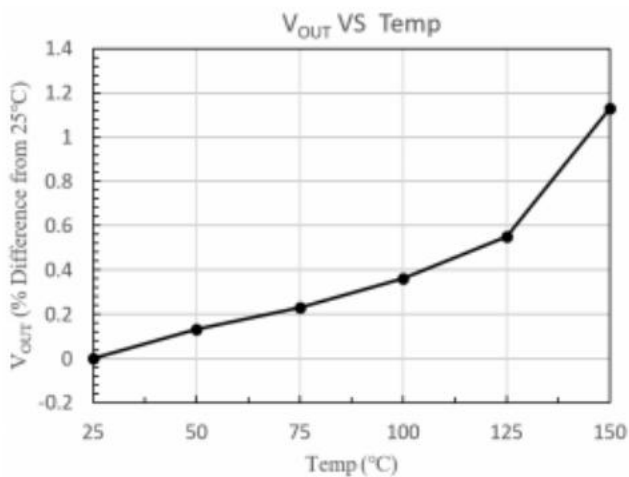
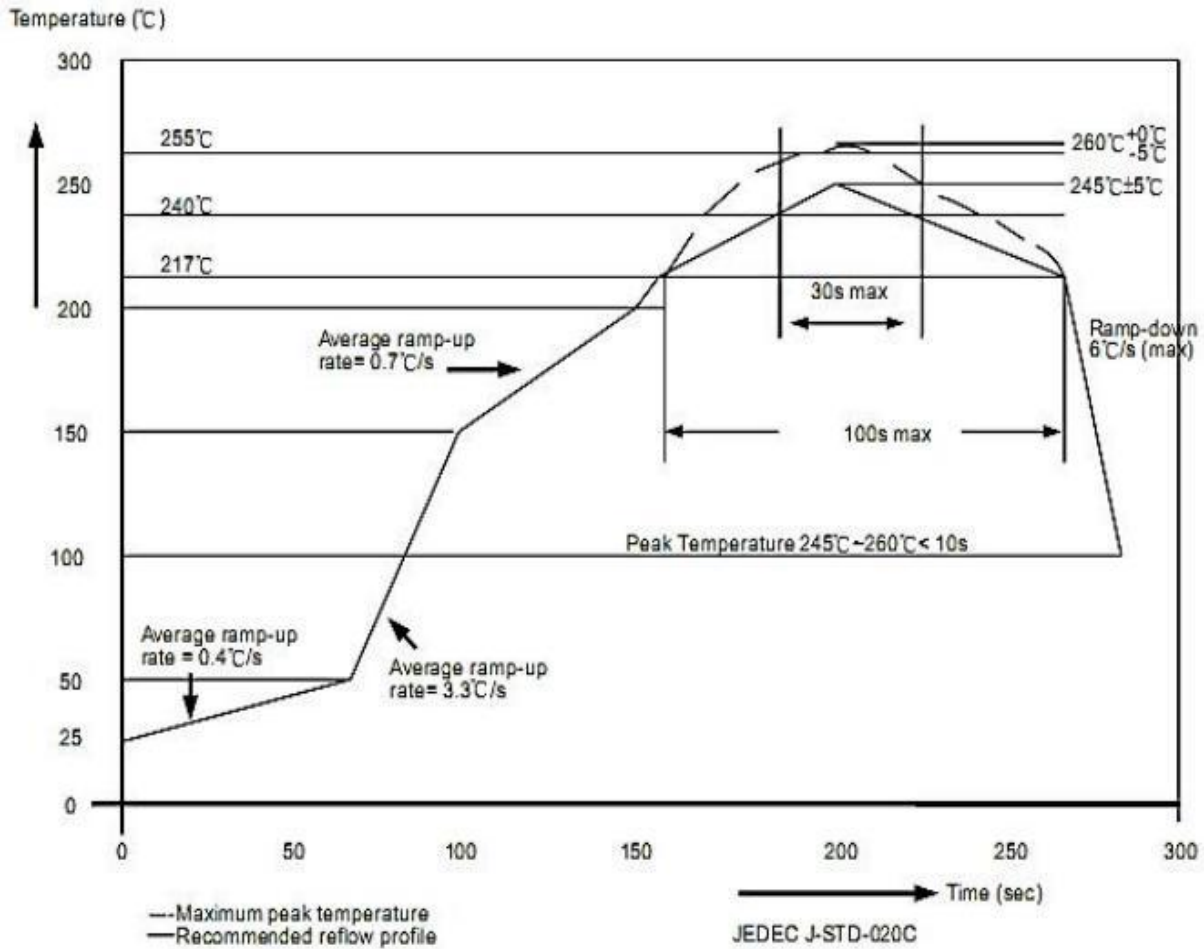


图 4 输出电压随温度变化 ($V_{IN}=10V, I_{OUT}=10mA$)

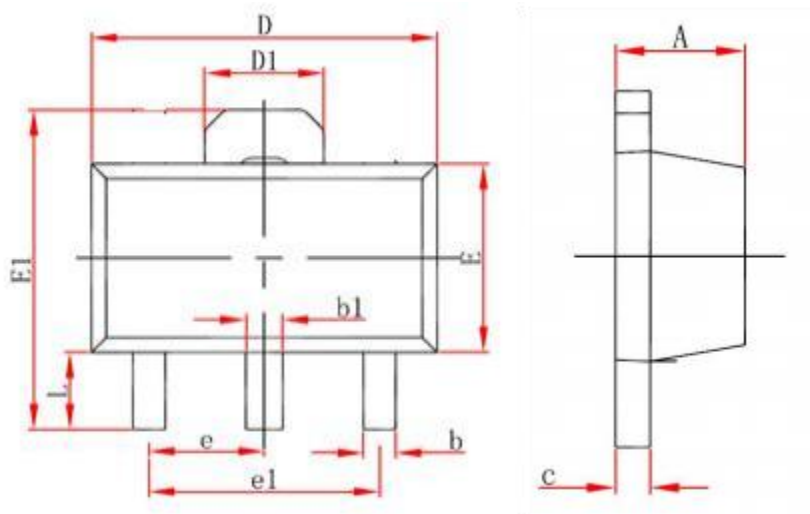


遵循欧洲 RoHs 标准，封装焊接制程锡炉温度符合 J-STD-020 标准

封装厚度	体积 $\text{mm}^3 < 350$	体积 $\text{mm}^3 : 350 \sim 2000$	体积 $\text{mm}^3 \geq 2000$
<1.6mm	260+0°C	260+0°C	260+0°C
1.6mm~2.5mm	260+0°C	250+0°C	245+0°C
≥2.5mm	250+0°C	245+0°C	245+0°C

PackageDimensions

SOT89-3



Symbol	Min(mm)	Max(mm)
A	1.3	1.8
b	0.2	0.7
b 1	0.25	0.75
c	0.2	0.6
D	4.3	4.8
E	2.2	2.8
E1	3.8	4.5
D1	1.55(REF)	
e	1.5(TYP)	
e 1	3.0(TYP)	
L	0.8	1.5



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